

CY20AAJ-8F

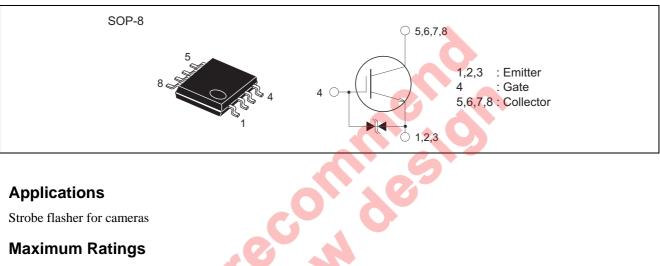
Nch IGBT for Strobe Flasher

REJ03G0281-0100 Rev.1.00 Aug.20.2004

Features

- V_{CES} : 400 V
- I_{CM} : 130 A
- Drive voltage : 4 V

Outline



Applications

Strobe flasher for cameras

Maximum Ratings

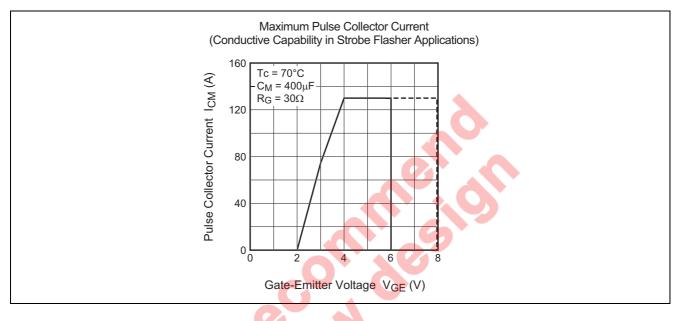
 $(Tc = 25^{\circ}C)$

Parameter	Symbol	Ratings	Unit	Conditions
Collector-emitter voltage	V _{CES}	400	V	$V_{GE} = 0 V$
Gate-emitter voltage	V _{GES}	±6	V	$V_{CE} = 0 V$
Peak gate-emitter voltage	V _{GEM}	±8	V	$V_{CE} = 0 V$, tw = 10 s
Collector current (Pulse)	Ісм	130	А	$C_{M} = 400 \ \mu F$
				(see performance curve)
Junction temperature	Тј	– 40 to +150	°C	
Storage temperature	Tstg	– 40 to +150	°C	

Electrical Characteristics

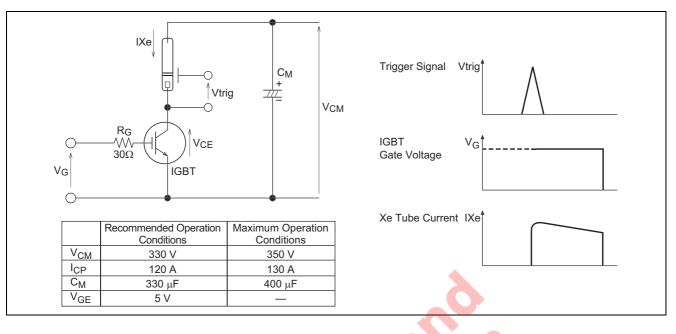
						$(Tch = 25^{\circ}C)$
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Collector-emitter breakdown voltage	V _{(BR)CES}	450	—	_	V	$I_C = 1 \text{ mA}, V_{GE} = 0 \text{ V}$
Gate-emitter breakdown voltage	$V_{(BR)GES}$	±8	—	_	V	$I_G = \pm 100 \ \mu A$, $V_{CE} = 0 \ V$
Collector-emitter leakage current	ICES	—	—	10	μΑ	$V_{CE} = 400 \text{ V}, V_{GE} = 0 \text{ V}$
Gate-emitter leakage current	I _{GES}	—	—	±10	μΑ	$V_{GE} = \pm 6 \text{ V}, V_{CE} = 0 \text{ V}$
Gate-emitter threshold voltage	$V_{\text{GE(th)}}$	_	_	1.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$

Performance Curves





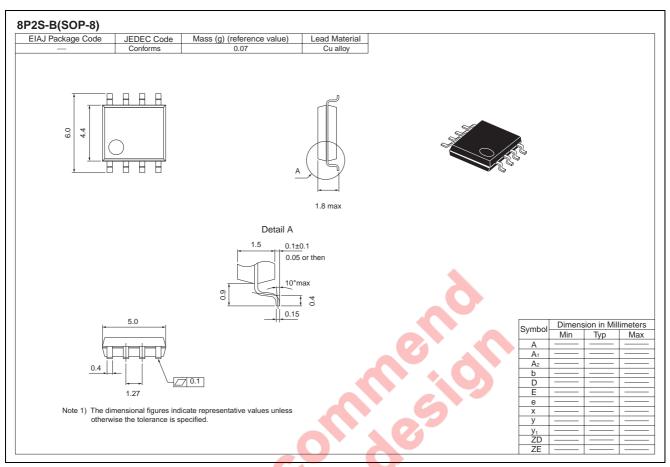
Application Example



Precautions on Usage

- 1. IGBT has MOS structure and its gate is insulated by thin silicon oxide. So please handle carefully to protect the device from electrostatic charge.
- 2. Gate drive voltage during on-period must be applied to satisfy the rating of maximum pulse collector current. And peak reverse gate current during turn-off must become less than 0.1 A. (In general, when $R_{G(off)} = 30 \Omega$, it is satisfied.)
- 3. The operation life should be endured 5,000 shots under the charge current ($I_{Xe} \le 130 \text{ A}$: full luminescence condition) of main capacitor ($C_M = 400 \ \mu\text{F}$) which can endure repeated discharge of 5,000 times. Repetition period under full luminescence condition is over 3 seconds.
- 4. Total operation hours applied to the gate-emitter voltage must be within 5,000 hours.

Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Surface-mounted type	Taping	3000	Type name – T +Direction (1 or 2)+3	CY20AAJ-8F-T13
Surface-mounted type	Plastic Magazine (Tube)	100	Type name	CY20AAJ-8F

Note : Please confirm the specification about the shipping in detail.

Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Keep safety first in your circuit designs! 1. Renesas Technology Corp. puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

- Notes regarding these materials 1. These materials are intended as a reference to assist our customers in the selection of the Renesas Technology Corp. product best suited to the customer's application; they do not convey any license under any intellectual property rights, or any other rights, belonging to Renesas Technology Corp. or a third party. 2. Renesas Technology Corp. assumes no responsibility for any damage, or infringement of any third-party's rights, originating in the use of any product data, diagrams, charts, programs, algorithms, or circuit application examples contained in these materials. 3. All information contained in these materials, including product data, diagrams, charts, programs and algorithms represents information on products at the time of publication of these materials, and are subject to change by Renesas Technology Corp. without notice due to product improvements or other reasons. It is therefore recommended that customers contact Renesas Technology Corp. or an authorized Renesas Technology Corp. product distributor for the latest product information before purchasing a product listed herein.

- therefore recommended that customers contact Renessas Technology Corp. or an authorized Renessas Technology Corp. product distributor for the latest product information before purchasing a product listed herein.
 The information described here may contain technical inaccuracies or typographical errors. Renessas Technology Corp. assumes no responsibility for any damage, liability, or other loss rising from these inaccuracies or errors. Please also pay attention to information published by Renessas Technology Corp. by various means, including the Renessas Technology Corp. Semiconductor home page (http://www.renessas.com).
 4. When using any or all of the information contained in these materials, including product data, diagrams, charts, programs, and algorithms, please be sure to evaluate all information as total system before making a final decision on the applicability of the information and products. Renessas Technology Corp. assumes no responsibility for any damage, liability or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact Renessas Technology Corp. or an authorized Renessas Technology Corp. product distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use. use.
- use. 6. The prior written approval of Renesas Technology Corp. is necessary to reprint or reproduce in whole or in part these materials. 7. If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or reexport contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited. 8. Please contact Renesas Technology Corp. for further details on these materials or the products contained therein.



http://www.renesas.com

RENESAS SALES OFFICES

Renesas Technology America, Inc. 450 Holger Way, San Jose, CA 95134-1368, U.S.A Tel: <1> (408) 382-7500 Fax: <1> (408) 382-7501

Renesas Technology Europe Limited. Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, United Kingdom Tel: <44> (1628) 585 100, Fax: <44> (1628) 585 900

Renesas Technology Europe GmbH Dornacher Str. 3, D-85622 Feldkirchen, Germany Tel: <49> (89) 380 70 0, Fax: <49> (89) 929 30 11

Renesas Technology Hong Kong Ltd. 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2375-6836

Renesas Technology Taiwan Co., Ltd. FL 10, #99, Fu-Hsing N. Rd., Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology (Shanghai) Co., Ltd. 26/F., Ruijin Building, No.205 Maoming Road (S), Shanghai 200020, China Tel: <86> (21) 6472-1001, Fax: <86> (21) 6415-2952

Renesas Technology Singapore Pte. Ltd. 1, Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001